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IN THE CLAIMS

Please amend claim 25 as follows:

- 1. (Previously Presented) A field emission display, comprising:
- a first substrate;

an electron emission assembly arranged on said first substrate;

a second substrate arranged a predetermined distance from said first substrate, said first and second substrates forming a vacuum space;

an illumination assembly arranged on said second substrate, said illumination assembly being illuminated by electrons emitted from said electron emission assembly;

a mesh grid arranged above said electron emission assembly, the mesh grid including an effective screen portion having a plurality of beam passage holes arranged in a predetermined pattern and having an inactive portion absent any beam passage holes; and a focusing electrode arranged on said mesh grid.

- 2. (Original) The field emission display of claim 1, wherein said mesh grid comprises a metal.
- 3. (Original) The field emission display of claim 1, wherein said mesh grid comprises one of stainless steel, invar, and an iron-nickel alloy.

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- 4. (Original) The field emission display of claim 3, wherein the iron-nickel alloy comprises 2.0 to 10.0 wt% of Cr.
- 5. (Original) The field emission display of claim 3, wherein the iron-nickel alloy comprises 40.0 to 44.0 wt% of Ni.
- 6. (Original) The field emission display of claim 3, wherein the iron-nickel alloy comprises 0.2 to 0.4 wt% of Mn, 0.7 wt% or less of C, and 0.3 wt% or less of Si.
- 7. (Original) The field emission display device of claim 1, wherein the thermal expansion coefficient of said mesh grid is in the range of 9.0 x 10⁻⁶/°C to 10.0 x 10⁻⁶/°C.
- 8. (Original) The field emission display device of claim 1, wherein electron emission assembly comprises a cathode and a gate and an electron emission source.
- 9. (Previously Presented) The field emission display device of claim 8, wherein said gate is arranged on an upper side of said cathode.
- 1 10. (Previously Presented) The field emission display device of claim 8, wherein the gate is arranged on a lower side of said cathode.

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- 1 11. (Original) The field emission display device of claim 1, wherein an intermediate
 2 material is arranged between said electron emission assembly and said mesh grid.
- 1 12. (Previously Presented) The field emission display device of claim 11, wherein said intermediate material comprises an insulating material.
- 1 13. (Previously Presented) The field emission display device of claim 11, wherein said intermediate material comprises a resistive material.

Claim 14. (Canceled)

- 15. (Previously Presented) A field emission display device, comprising:
- 2 a first substrate;

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- an electron emission assembly arranged on said first substrate;
- a second substrate arranged a predetermined distance from said first substrate, said first and second substrates forming a vaccum assembly;
 - an illumination assembly arranged on said second substrate, said illumination assembly being illuminated by electrons emitted from said electron emission assembly; and
 - a mesh grid arranged above said electron emission assembly, the mesh grid including an effective screen portion having a plurality of beam passage holes arranged in a predetermined pattern and having an inactive portion absent any beam passage holes;

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wherein said mesh grid is bonded to said electron emission assembly by a frit.

- 1 16. (Previously Presented) A method of manufacturing a field emission display, the
 2 method comprising:
- 3 providing a first substrate;
- arranging an electron emission assembly on said first substrate;
- arranging a second substrate a predetermined distance from said first substrate to form
- a vacuum space with said first and second substrates;
 - arranging an illumination assembly on said second substrate, and illuminating said
 illumination assembly with electrons emitted from said electron emission assembly;
 - arranging a mesh grid above said electron emission assembly, the mesh grid including an effective screen portion having a plurality of beam passage holes arranged in a predetermined pattern and having an inactive portion absent any beam passage holes; and a focusing electrode arranged on said mesh grid.
- 1 17. (Original) The method of claim 16, further comprising forming said mesh grid of a metal.
- 1 18. (Original) The method of claim 16, further comprising forming said mesh grid
 2 of one of stainless steel, invar, and an iron-nickel alloy.

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- 1 19. (Original) The method of claim 16, further comprising forming a cathode and a gate and an electron emission source in said electron emission assembly.
- 20. (Original) The method of claim 19, further comprising forming said gate on one of an upper an lower side of said cathode.
- 21. (Original) The method of claim 16, further comprising forming an intermediate material between said electron emission assembly and said mesh grid.
- 1 22. (Original) The method of claim 21, further comprising forming said intermediate
 2 material of an insulating material.
- 23. (Original) The method of claim 21, further comprising forming said intermediate material of a resistive material.

Claim 24. (Canceled)

- 25. (Currently Amended) A method of manufacturing a field emission display device, the method comprising:
- 3 providing a first substrate;
- 4 arranging an electron emission assembly on said first substrate;

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- arranging a second substrate a predetermined distance from said first substrate to form

 a vaccum vacuum assembly with said first and second substrates;
- arranging an illumination assembly on said second substrate and illuminating said illumination assembly with electrons emitted from said electron emission assembly;
 - arranging a mesh grid above said electron emission assembly the mesh grid including an effective screen portion having a plurality of beam passage holes arranged in a predetermined pattern and having an inactive portion absent any beam passage holes; and bonding said mesh grid to said electron emission assembly with a frit.